Product data sheet

1. General description

Standard reverse recovery power diode in a TO220F package.





2. Features and benefits

- · Low forward voltage drop
- Low leakage current
- · High voltage capability
- · High inrush current capability

3. Applications

- · Input rectifier
- · Bypass diode

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit				
Absolute	Absolute maximum rating									
V_{RRM}	repetitive peak reverse voltage		800				V			
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; Fig. 1; Fig. 2		3	5		Α			
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	400			Α				
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	435		А					
Symbol	Parameter	Conditions	Min Typ Max		Max	Unit				
Static ch	aracteristics									
V _F	forward voltage	I _F = 20 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.05	1.25	V			
		I _F = 20 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.00	1.20	V			
		I _F = 35 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.18	1.40	V			
		I _F = 35 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.15	1.35	V			

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	K — A
2	А	anode		001aaa020
mb	n.c.	mounting base; isolated		

6. Ordering information

Table 3. Ordering information

Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		
WND35P08X	TO220F-2L	WND35P08XQ	Tube	50	SOD113A	10-April-2014		

7. Marking

Table 4. Marking codes

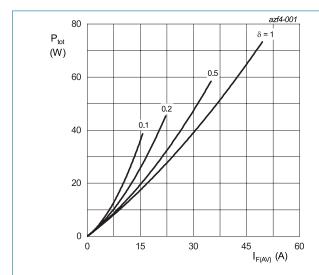
Type number	Marking codes
WND35P08X	WND35P08X

8. Limiting values

Table 5. Limiting values

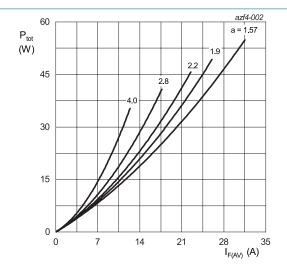
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		800	V
V_{RWM}	crest working reverse voltage		800	V
V _R	reverse voltage	DC	800	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; Fig. 1; Fig. 2	35	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	400	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	435	Α
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 10 \text{ms}$	800	A ² s
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		-40 to 150	°C



$$\begin{split} I_{\text{F(AV)}} &= I_{\text{F(RMS)}} \times \sqrt{\delta} \\ V_{\text{o}} &= 1.025 \text{ V; } R_{\text{s}} = 0.0092 \text{ } \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}$ / $I_{F(AV)}$ V_o = 1.025 V; R_s = 0.0092 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

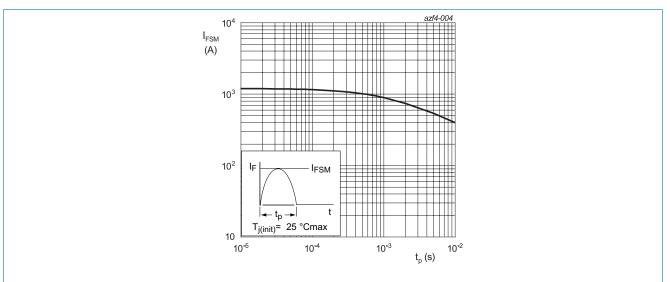
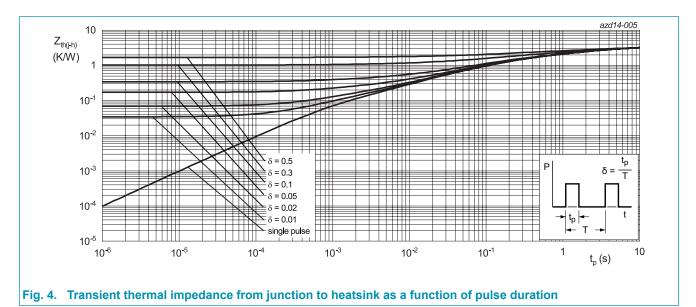


Fig. 3. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	Fig. 4	-	-	3.2	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



10. Isolation characteristics

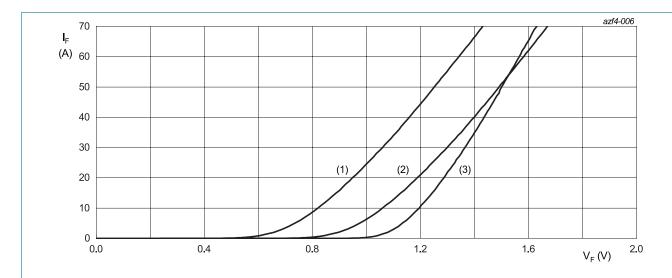
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from cathode to external heatsink	-	10	-	PF

11. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Static characteristics									
V _F forward current		I _F = 20 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.05	1.25	V		
		I _F = 20 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.00	1.20	V		
		I _F = 35 A; T _j = 25 °C; <u>Fig. 5</u>		I _F = 35 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.18	1.40	V
		I _F = 35 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.15	1.35	V		
I _R	reverse current	V _R = 1600 V; T _j = 25 °C		-	-	50	μA		
		V _R = 1600 V; T _j = 150 °C		-	-	1	mA		

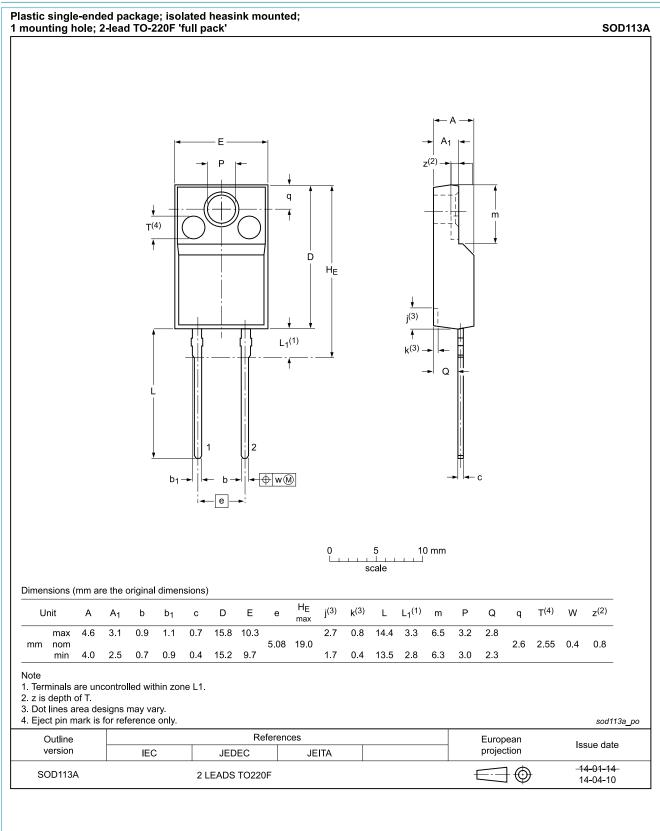


 V_o = 1.025 V; R_s = 0.0092 Ω

(1) $T_i = 150 \,^{\circ}\text{C}$; typical values (2) $T_j = 150 \,^{\circ}\text{C}$; maximum values (3) $T_j = 25 \,^{\circ}\text{C}$; maximum values

Fig. 5. Forward current as a function of forward voltage

12. Package outline



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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